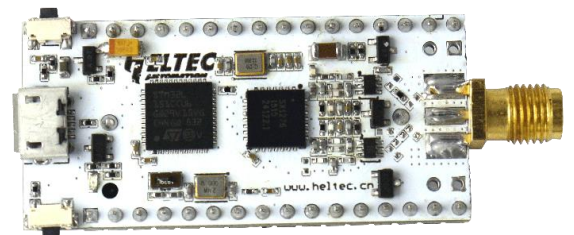




## LoRa Node 151

## LoRa Node Development Kit





## Document version

Version	Time	Description
V1.0	2017-06-01	Documents creating
V2.0	2019-10-20	Document structure update
V2.2	2020-04-01	Document structure update



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# 1. Description

## 1.1 Overview

Based on ultra low power design, we launched LoRa Node 151 , adopting the [STM32L151CCU6](#) MCU (support DFU mode) and SX127x LoRa chip, use 1/2 AA Lithium chlorine sulfite battery. Enter low power mode under the standard LoRaWAN protocol, the Deep Sleep Current  $\leq 1.8\mu\text{A}$ .

LoRa Node 151 are available in two product variants:

Table 1.1 Product model list

No.	Model	Description
1	LoRa-Node-151-L	470~510MHz working LoRa frequency, used for China mainland (CN470) LPW band.
2	LoRa-Node-151-F	For EU868, IN865, US915, AU915, AS923, KR920 and other LPW networks with operating frequencies between 863~928MHz.

## 1.2 Product features

- CE Certificate;
- Microprocessor: [STM32L151CCU6](#)(ARM® Cortex®-M3 32-bit RISC core,support DFU mode) , with LoRa® node chip SX1276/SX1278;
- Onboard user resources available: 256 Kbytes of Flash memory with ECC; 32 Kbytes of RAM; 8 Kbytes of true EEPROM with ECC; 128-byte backup register;



- Micro USB interface with a complete voltage regulator, ESD protection, short circuit protection, and other protection measures;
- 1/2 AA battery shell, use 1/2 AA Lithium chlorine sulfite battery (this battery can't charge, but onboard USB / battery power automatic switching allows connect USB when the battery is assembled);
- Reserve SMA antenna interface for LoRa use;
- Download the firmware via DFU or ST-LINK;
- Provide complete LoRaWAN(ClassA/C) source code(support ABP and OTAA);
- With good RF circuit design and basic low-power design (sleep current: 1.8uA), it is convenient for IoT application vendors to quickly verify solutions and deploy applications.

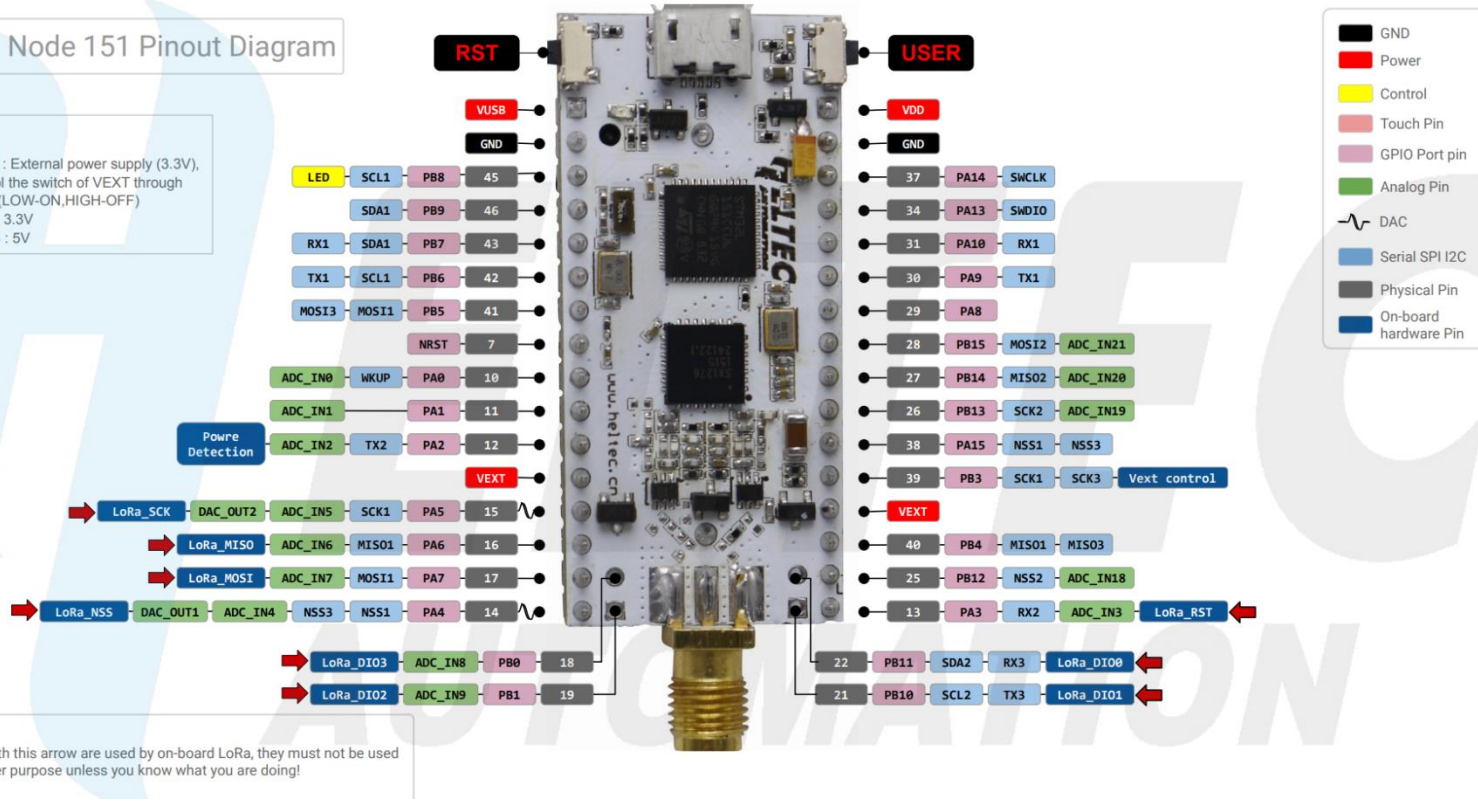
## 2. Pin Definition

### 2.1 Pin assignment

LoRa Node 151 Pinout Diagram

Notes:

- VEXT : External power supply (3.3V), control the switch of VEXT through GPIO(LOW-ON,HIGH-OFF)
- VDD : 3.3V
- VUSB : 5V



### 2.2 Pin description

#### Header P1

Table 2-2-1 Pin description

No.	Name	Type	Function
1	VUSB	P	5V Input/Output.
2	GND	P	Ground.
3	PB8	P	PB8, SCL1, LED.
4	PB9	P	PB9, SDA1.
5	PB7	I/O	PB7, SDA1, RX1.
6	PB6	I/O	PB6, SCL1, TX1.
7	PB5	I	PB5, MOSI1, MOSI3.
8	NRST	I/O	RESET.

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9	PA0	I/O	PA0, WKUP, ADC_IN0.
10	PA1	I/O	PA1, ADC_IN1.
11	PA2	I/O	PA2, TX2, ADC_IN2 <sup>1</sup> .
12	VEXT	I/O	Output 3.3V, power supply for external device.
13	PA5	I/O	PA5, SCK1, ADC_IN5, DAC_OUT2, LoRa_SCK.
14	PA6	I/O	PA6, MISO1, ADC_IN6, LoRa_MISO.
15	PA7	I/O	PA7, MOSI1, ADC_IN7, LoRa_MOSI.
16	PA4	I/O	PA4, NSS1, NSS3, ADC_IN4, DAC_OUT1, LoRa_NSS.

### Header P2

Table 2-2-2 Pin description

No.	Name	Type	Function
1	VDD	P	3.3V Input/Output.
2	GND	P	Ground.
3	PA14	P	PA14, SWCLK.
4	PA13	I/O	PA13, SWDIO.
5	PA10	I/O	PA10, RX1.
6	PA9	I/O	PA9, TX1.
7	PA8	I/O	PA8.
8	PB15	I/O	PB15, MOSI2, ADC_IN21.
9	PB14	I/O	PB14, MISO2, ADC_IN20.
10	PB13	I/O	PB13, SCK2, ADC_IN19.
11	PA15	I/O	PA15, NSS1, NSS3.
12	PB3	I/O	PB3, SCK1, SCK3, VEXT_Control.
13	VEXT	I/O	Output 3.3V, power supply for external device.
14	PB4	I/O	PB4, MISO1, MISO3.
15	PB12	I/O	PB12, NSS2, ADC_IN18.
16	PA3	I/O	PA3, RX2, ADC_IN3, LoRa_RST.

### Header P3

Table 2-2-3 Pin description

<sup>1</sup> ADC\_IN2 is used to read the lithium battery voltage, the voltage of the lithium battery is:  $VBAT = 3.2 * V(ADC\_IN2)$ .





No.	Name	Type	Function
1	PB0	I/O	PB0, ADC_IN8, LoRa_DIO3.
2	PB1	I/O	PB1, ADC_IN9, LoRa_DIO2.

#### Header P4

Table 2-2-4 Pin description

No.	Name	Type	Function
1	PB11	I/O	PB11, SDA2, RX3, LoRa_DIO0.
2	PB10	I/O	PB10, SCL2, TX3, LoRa_DIO1.



### 3. Specifications

#### 3.1 General specifications

Table 3-1: General specifications

Parameters	Description
Master Chip	STM32L151CCU6(Ultra-low-power 32-bit MCU ARM®-based Cortex®-M3)
LoRa Chipset	SX1276/SX1278
Frequency	470~510 MHz, 863~923 MHz
Max TX Power	19dB ± 1dB
Receiving sensitivity	-135 dBm
Hardware Resource	USART x 3; SPI x 2; I2C x 2; I2S x 2; 12-bits ADC input x 25; 12-bits DAC output x 2; GPIO x 29
Memory	256KB internal FLASH; 32KB internal SRAM
Interface	Micro USB x 1; LoRa Antenna interface(SMA) x 1; 16 x 2.54 pin x 2 + 2 x 2.54 pin x 2
Battery	1/2AA Lithium
Operating temperature	-20 ~ 70 °C
Dimensions	56.6 x 24 x 20 mm
Low Power	Deep Sleep 2.5uA

#### 3.2 Power supply

Except when USB or 5V Pin is connected separately, lithium battery can be connected to charge it. In other cases, only a single power supply can be connected.



Table 3-2: Power supply

Power supply mode	Minimum	Typical	Maximum	Company
USB powered( $\geq 500\text{mA}$ )	4.7	5	6	V
Lithium battery( $\geq 250\text{mA}$ )	3.3	3.6	4.2	V
5V pin( $\geq 500\text{mA}$ )	4.7	5	6	V
3V3 pin( $\geq 150\text{mA}$ )	2.7	3.3	3.5	V

### 3.3 Power output

Table 3-3: Power output

Output Pin	Minimum	Typical	Maximum	Company
3.3V Pin			500	mA
5V Pin (USB Powered only)		Equal to the input current		
Vext Pin			350	mA

### 3.4 Power characteristics

Table 3-4: Power characteristics

Mode	Condition	Min.	Typical	Max.	Company
Power Consumption(mA)	LoRa 10dB output		50		mA
	LoRa 12dB output		60		mA
	LoRa 15dB output		110		mA
	LoRa 20dB output		130		mA



### 3.5 LoRa RF characteristics

#### 3.5.1 Transmit power

Table3-5 Transmit power

Operating frequency band	Maximum power value/[dBm]
470~510	19 ± 1
867~870	19 ± 1
902~928	19 ± 1

#### 3.5.2 Receiving sensitivity

The following table gives typically sensitivity level of the LoRa-Node-151-(L/H).

Table3-6: Receiving sensitivity

Signal Bandwidth/[KHz]	Spreading Factor	Sensitivity/[dBm]
125	SF12	-135
125	SF10	-130
125	SF7	-124

### 3.6 Operation Frequencies

LoRa Node 151(F) supports LoRaWAN frequency channels and models corresponding table.

Table3-7: Operation Frequencies

Region	Frequency (MHz)	Model
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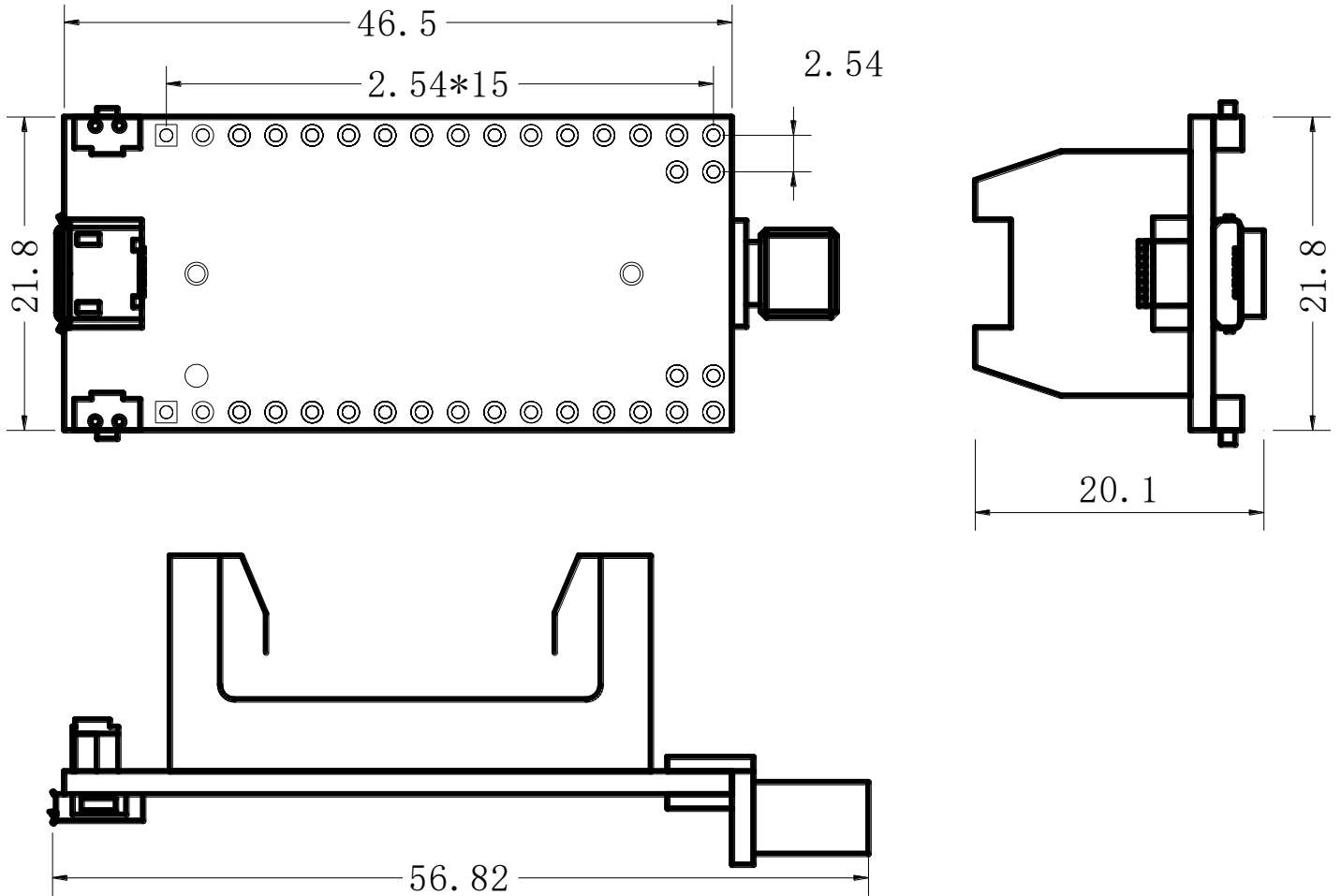


<b>EU433</b>	433.175~434.665	LoRa-Node-151-L
<b>CN470</b>	470~510	LoRa-Node-151-L
<b>IN868</b>	865~867	LoRa-Node-151-F
<b>EU868</b>	863~870	LoRa-Node-151-F
<b>US915</b>	902~928	LoRa-Node-151-F
<b>AU915</b>	915~928	LoRa-Node-151-F
<b>KR920</b>	920~923	LoRa-Node-151-F
<b>AS923</b>	920~925	LoRa-Node-151-F



## 4. Hardware resource

### 4.1 Physical dimensions





## 5. Resource

### 5.1 Relevant Resource

- [Schematic diagram](#)
- [Pin map](#)
- [Downloadable resource](#)

### 5.2 Contact Information

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